

MPFF600R12MBF

1200V600A IGBT Module

Electrical Features

- Trench/Fieldstop IGBT
- Low VCE(sat)
- VCE(sat) with positive temperature coefficient
- 10 µ s short circuit capability
- Fast&soft reverse recovery anti-parallel FWD
- Low inductance case



Typical Applications

- Motor Drives
- High Power Converters
- UPS System
- Servo Drives
- Wind Turbines

IGBT, Inverter

Maximu	m Rated Values						
Symbol	Item	Conditions			Rating		Unit
IGBT							
V _{CES}	Collector-emitter voltage	T _{vj} =25°C	$T_{vj}=25$ °C			1200	
V _{GES}	Gate-emitter voltage	-			±20		V
$I_{\rm C}$	Collector current,DC	T _C =100°C,T _{vj} =175°	°C		600		A
I _{CRM}	Repetitive peak collector current	t _p =1ms			1200		A
t _{SC}	Short circuit withstand time	V _{GE} =15V, V _{CC} =600	0V, T _{vj} ≤150°C		10		μs
P _{tot}	Total power dissipation	T _C =25°C,T _{vj} =175°C	C		4838		W
Characte	eristics Values						
Symbol	Item	Conditions			Values		Unit
IGBT				Min.	Тур.	Max.	
I _{CES}	Collector-emitter cut-off current	V _{CE} =1200V,V _{GE} =0V,T _{vj} =25°C		-	-	3	mA
I _{GES}	Gate leakage current	V _{CE} =0V,V _{GE} =20V,T _{vj} =25°C		-	-	400	nA
$V_{\text{GE(th)}}$	Gate-emitter threshold voltage	$I_C=23$ mA, $V_{CE}=V_{GE}$, $T_{vj}=25$ °C		5.0	5.7	7.0	
	Collector-emitter saturation voltage	I _C =600A V _{GE} =15V	T _{vj} =25°C	-	2.2	2.4	V
V _{CEsat}			T _{vj} =125°C	-	2.7	-	_ v
			T _{vj} =150°C	-	2.9	-	
Cies	Input capacitance	V -25VV -0V	N. OCHAN ON		49.77	-	
Coes	Output capacitance	$V_{CE}=25V, V_{GE}=0V$ $f=1MHz, T_{vj}=25$ °C		-	2.28	-	nF
Cres	Reverse transfer capacitance			-	2.22	-	
Q _G	Gate charge	$V_{GE}=\pm 15V$		-	7.5	-	nC
Rg	Internal gate resistance	T _{vj} =25°C		-	0.28	-	Ω

$t_{d(on)}$	Turn-on delay time		T _{vj} =25°C	-	272	-	
			T _{vj} =125°C	-	253	-	
			T _{vj} =150°C	-	249	-	
$t_{\rm r}$			T_{vj} =25°C	-	264	-	
	Rise time		T _{vj} =125°C	-	262	-	
			T _{vj} =150°C	-	259	-	
	Turn-off delay time	$V_{\text{CC}}=600\text{V},$	T _{vj} =25°C	-	1019	-	ns
$t_{d(off)}$		I _C =600A,	$T_{vj}=125$ °C	-	1096	_	
,		$V_{GE}=\pm 15V$	T _{vj} =150°C	-	1112	_	
		$R_{G(on)}=5.1 \Omega$	T _{vi} =25°C	-	144	_	
t_{f}	Fall time	$R_{G(off)}=5.1 \Omega$,	T _{vi} =125°C	-	195	-	
		L _{load} =200uH	T _{vi} =150°C	_	225	_	
		_	$T_{vi}=25$ °C	_	148.5	_	
Eon	Turn-on energy (per pulse)		$T_{vi}=125$ °C	_	159.4	_	
—011	($T_{vj}=150$ °C	_	166.9	_	
		-	$T_{vj}=25^{\circ}C$	_	83.9	_	mJ
E_{off}	Turn-off energy (per pulse)		$T_{vj}=125$ °C	_	95.6	_	
Lon			$T_{vj} = 150^{\circ}C$	_	99.3	_	-
R _{thJC}	Thermal resistance, junction to case	per IGBT	1 Vj 130 C	_	-	0.031	K/W
RthCH	Thermal resistance, case to heatsink	per IGBT / λgrease=1W/(m·K)			0.035	0.031	K/W
TUNCH	Temperature under switching	per 10D1/ rigidas	sc-1 w/(iii K)	_	0.033		IX/ VV
$T_{vjop} \\$	conditions			-40		150	°C
	m Rated Values						
0 1 1			1:4:		D.	•	TT '4
Symbol	Item		onditions			ting	Unit
V _{RRM}	Item Repetitive peak reverse voltage	T _{vj} =25°C			12	200	V
V _{RRM}	Item Repetitive peak reverse voltage Forward current,DC	T _{vj} =25°C T _C =100°C,T _{vj} =15			12	200	V A
V _{RRM} I _F I _{FRM}	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current	T _{vj} =25°C			12	200	V
V _{RRM} I _F I _{FRM}	Item Repetitive peak reverse voltage Forward current,DC	T _{vj} =25°C T _C =100°C,T _{vj} =15	50°C		12 60 12	200	V A
V _{RRM} I _F I _{FRM} Characte	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values	T_{vj} =25°C T_{C} =100°C, T_{vj} =15 t_{p} =1ms	T _{vj} =25°C	-	12 60 12 2.28	200	V A A
V _{RRM} I _F I _{FRM}	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current	T_{vj} =25°C T_{C} =100°C, T_{vj} =15 t_{p} =1ms	T _{vj} =25°C T _{vj} =125°C	-	12 60 12 2.28 2.51	200	V A
V _{RRM} I _F I _{FRM} Characte	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values	T_{vj} =25°C T_{C} =100°C, T_{vj} =15 t_{p} =1ms			12 60 12 2.28 2.51 2.53	200	V A A
V _{RRM} I _F I _{FRM} Characte	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage	T_{vj} =25°C T_{C} =100°C, T_{vj} =15 t_{p} =1ms		-	2.28 2.51 2.53 159.5	200	V A A
V _{RRM} I _F I _{FRM} Characte	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values	T_{vj} =25°C T_{C} =100°C, T_{vj} =15 t_{p} =1ms		-	2.28 2.51 2.53 159.5 228.4	200	V A A
V _{RRM} I _F I _{FRM} Characte V _F	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage	T_{vj} =25°C T_{C} =100°C, T_{vj} =15 t_{p} =1ms		-	2.28 2.51 2.53 159.5 228.4 249.4	200	V A A V
V _{RRM} I _F I _{FRM} Characte V _F	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage	T_{vj} =25°C T_{C} =100°C, T_{vj} =15 t_{p} =1ms		- - -	2.28 2.51 2.53 159.5 228.4	200	V A A V
V _{RRM} I _F I _{FRM} Characte V _F	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage	T_{vj} =25°C T_{C} =100°C, T_{vj} =15 t_{p} =1ms I_{F} =600A V_{GE} =0V		- - - -	2.28 2.51 2.53 159.5 228.4 249.4	200	V A A
V _{RRM} I _F I _{FRM} Characte V _F	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current	T_{vj} =25°C T_{C} =100°C, T_{vj} =15 t_{p} =1ms I_{F} =600A V_{GE} =0V		- - - -	2.28 2.51 2.53 159.5 228.4 249.4 516.1	200 00 200 	V A A
V _{RRM} I _F I _{FRM} Characte V _F	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current	$T_{vj}=25^{\circ}C$ $T_{C}=100^{\circ}C, T_{vj}=15$ $t_{p}=1 \text{ms}$ $I_{F}=600A$ $V_{GE}=0V$ $V_{R}=600V$ $I_{F}=600A$		- - - - -	2.28 2.51 2.53 159.5 228.4 249.4 516.1 475.9	200 00 200	V A A
V _{RRM} I _F I _{FRM} Characte V _F	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current	T_{vj} =25°C T_{C} =100°C, T_{vj} =15 t_{p} =1ms I_{F} =600A V_{GE} =0V		- - - - - -	2.28 2.51 2.53 159.5 228.4 249.4 516.1 475.9 474.5		V A A
V _{RRM} I _F I _{FRM} Characte V _F I _{RM}	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current Reverse recovery time	$T_{vj}=25^{\circ}C$ $T_{C}=100^{\circ}C, T_{vj}=15$ $t_{p}=1 \text{ms}$ $I_{F}=600A$ $V_{GE}=0V$ $V_{R}=600V$ $I_{F}=600A$		- - - - - -	2.28 2.51 2.53 159.5 228.4 249.4 516.1 475.9 474.5 35.1		V A A V A ns
V _{RRM} I _F I _{FRM} Characte V _F I _{RM}	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current Reverse recovery time	$T_{vj}=25^{\circ}C$ $T_{C}=100^{\circ}C, T_{vj}=15$ $t_{p}=1 \text{ms}$ $I_{F}=600A$ $V_{GE}=0V$ $V_{R}=600V$ $I_{F}=600A$		- - - - - - -	2.28 2.51 2.53 159.5 228.4 249.4 516.1 475.9 474.5 35.1 55.8		V A A V A ns
V _{RRM} I _F I _{FRM} Characte V _F I _{RM}	Item Repetitive peak reverse voltage Forward current,DC Repetitive peak forward current eristic Values Continuous forward voltage Peak reverse recovery current Reverse recovery time	$T_{vj}=25^{\circ}C$ $T_{C}=100^{\circ}C, T_{vj}=15$ $t_{p}=1 \text{ms}$ $I_{F}=600A$ $V_{GE}=0V$ $V_{R}=600V$ $I_{F}=600A$		- - - - - - -	2.28 2.51 2.53 159.5 228.4 249.4 516.1 475.9 474.5 35.1 55.8 66.5	200 200 200 	V A A V A ns

R _{thJC}	Thermal resistance, junction to case	per diode	-	-	0.071	K/W
R _{thCH}	Thermalresistance,case to heatsink	per diode/ λgrease=1W/(m·K)	-	0.0395	-	K/W
T _{vjop}	Temperature under switching conditions		-40		150	°C

NTC Thermistor Characteristics

Symbol	Item	Conditions	Values			Unit
		Conditions	Min.	Typ.	Max.	
R ₂₅	Rated resistance	$T_{\rm C}$ =25°C	-	5	-	kΩ
$\Delta R/R$	Deviation of resistance	$T_{\rm C}=100$ °C, $R_{100}=493\Omega$	-5	-	5	%
P ₂₅	Power dissipation	T _C =25°C	-	-	20	mW
B _{25/50}	B-constant	$R_2=R_{25}\exp[B_{25/50}(1/T_2-1/(298.15K))]$	1	3375	-	
B _{25/80}	B-constant	$R_2=R_{25}\exp[B_{25/80}(1/T_2-1/(298.15K))]$	-	3411	-	K
B _{25/100}	B-constant	$R_2=R_{25}exp[B_{25/100}(1/T_2-1/(298.15K))$	-	3433	-	

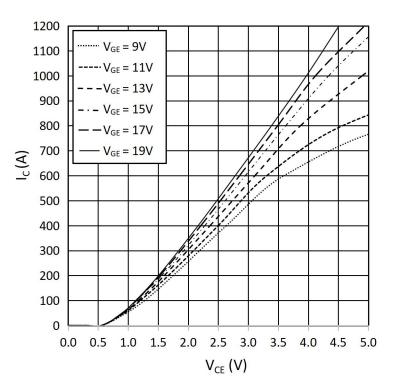
Module

Symbol	Item	Conditions	Rating		Unit	
V _{ISOL}	Isolation voltage	Terminals to baseplate, RMS,f=50Hz,t=1min	2500			V
-	Material of module baseplate	-	Cu		-	
-	Internal isolation	Basic insulation(class 1, IEC 61140)	Al ₂ O ₃			-
T _{stg}	Storage temperature	-	-40~125		5	°C
C11	Item	Constitution of	Values			Unit
Symbol		Conditions	Min.	Тур.	Max.	
M	Mounting torque for module mounting	Screw M6	3.0	-	5.0	Nm
	Terminal connection torque	Screw M6	2.5	-	5.0	Nm
ds	Creepage distance	Terminal to terminal	-	13	-	
		Terminal to base plate	-	14.5	-	mm
1	Clearance	Terminal to terminal	-	10	-	
da		Terminal to base plate	-	12.5	-	mm
m	Weight	-	-	340	_	g

output characteristic IGBT, Inverter (typical)

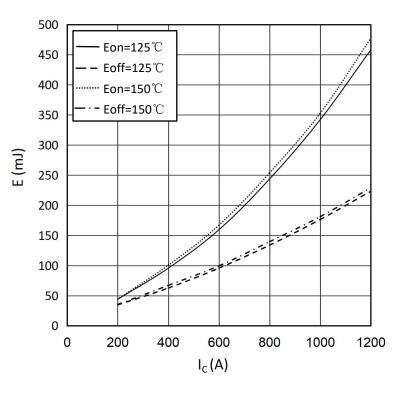
$$I_C = f(V_{CE})$$

 $T_{vj} = 150$ °C



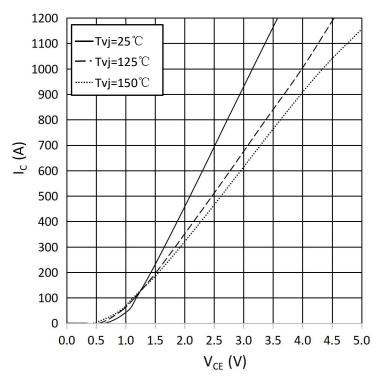
switching losses IGBT, Inverter(typical)

$$\begin{split} E_{on} &= f\left(I_{C}\right), \, E_{off} = f\left(I_{C}\right) \\ V_{GE} &= \pm 15 V, \, R_{Gon} = 5.1 \Omega, \, R_{Goff} = 5.1 \Omega, \, V_{CE} = 600 V \end{split}$$



output characteristic IGBT, Inverter (typical)

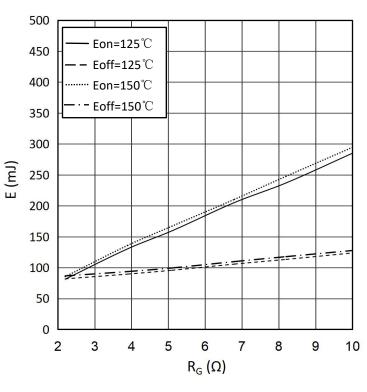
$$I_{C} = f(V_{CE})$$
$$V_{GE} = 15 \text{ V}$$



switching losses IGBT, Inverter(typical)

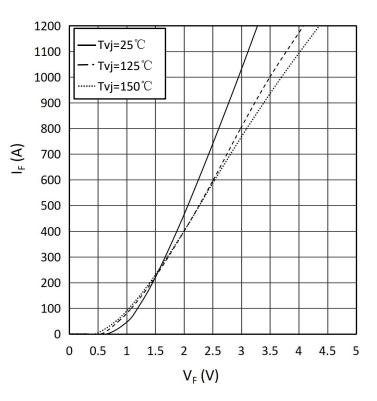
$$E_{on} = f(R_G), E_{off} = f(R_G)$$

 $V_{GE} = \pm 15V, I_C = 600A, V_{CE} = 600V$



forward characteristic of Diode, Inverter (typical)

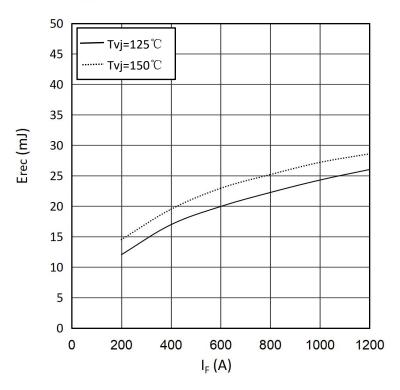
$$I_F = f(V_F)$$



switching losses Diode, Inverter (typical)

$$E_{rec} = f(I_F)$$

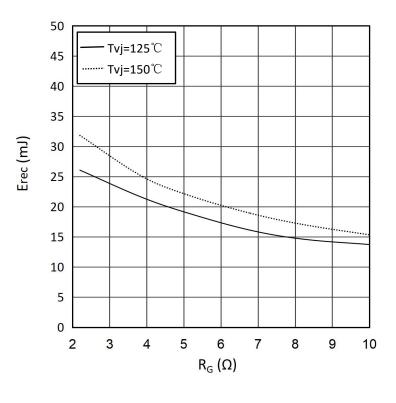
$$R_{Gon}=5.1\Omega$$
, $V_{CE}=600V$



switching losses Diode, Inverter (typical)

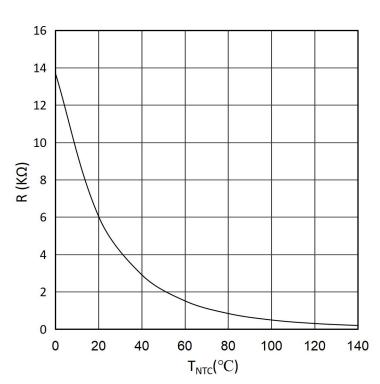
$$E_{rec} = f(R_G)$$

$$I_F = 600A, V_{CE} = 600V$$

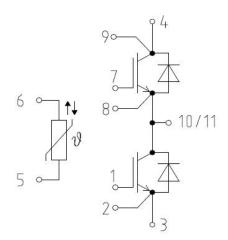


$NTC-Thermistor-temperature\ characteristic (typical)$

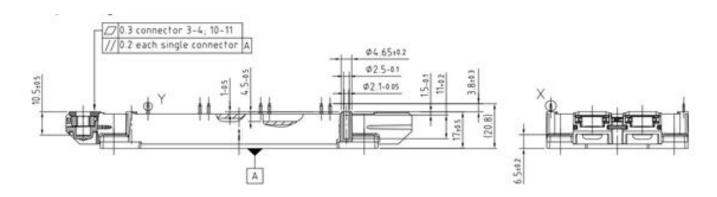
R=f(T)

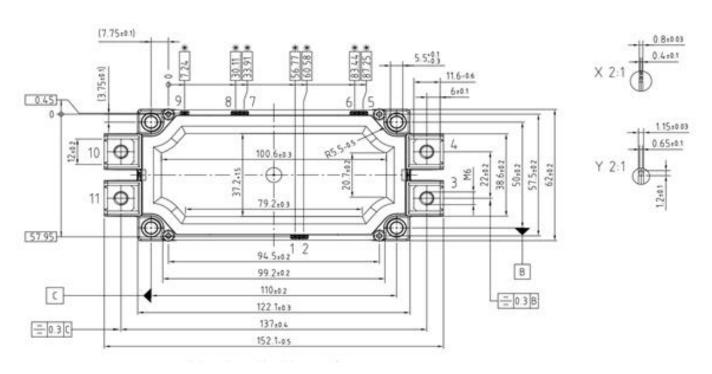


Circuit diagram headline



Package outlines (Unit: mm)





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